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BYX42 SERIES

SILICON RECTIFIER DIODES

Diffused silicon rectifier diodes in DO-4 metal envelopes, intended for power rectifier applications.

The series consists of the following types:

Normal polarity (cathode to stud): BYX42-300 to 1200, Reserve polarity (anode to stud): BYX42-300R to 1200R.

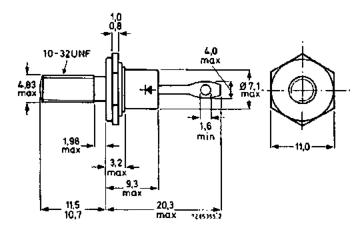
QUICK REFERENCE DATA

	Varm	BYX42-300(R)		600(R) 1200(R)		
Repetitive peak reverse voltage		max.	300	600	1200 V	
Average forward current	IF(AV)	max.		12 A		
Non-repetitive peak forward current	IFSM	max,		125	Α	

MECHANICAL DATA

Dimensions in mm

DO-4



Net mass: 6 g

Diameter of clearance hole: 5,2 mm

Accessories supplied on request: see ACCESSORIES section

Torque on nut: min. 0,9 Nm

(9 kg cm)

max. 1,7 Nm

(17 kg cm)

Supplied with device: 1 nut, 1 lock washer Nut dimensions accross the flats: 9,5 mm

The mark shown applies to normal polarity types.

NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

Quality Semi-Conductors

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BYX42 SERIES

RATINGS Limiting values in accorden	ce with th	e Absolu	ıte Max in	ıum Syste	em (IEC	134)
		2-300(R)	600(R)	1200(R		
Non-repetitive peak reverse voltage (t ≤ 10 ms)	v_{RSM}	max.	300	600	1200	v
Repetitive peak reverse voltage (δ ≤ 0,01)	v _{rrm}	max.	300	600	1200	v
Crest working reverse voltage	VRWM	max.	200	400	800	v
Continuous reverse voltage	v_R	max.	200	400	800	V
Currents			-	·		
Average forward current (averaged over any 20 ms period) up to $T_{mb} = 115$ °C at $T_{mb} = 125$ °C				max. max.	12 10	A A
R.M.S. forward current			I _{F(RMS)} max.		20	A
Repetitive peak forward current				max.	60	A
Non-repetitive peak forward current (t = 10 ms; half sine-wave) T _j = 175 with reapplied V _{RWM} max	°C prior to	surge;	t _{FSM}	max.	125	A
Temperatures						
Storage temperature	orage temperature			T _{stg} -55 t		٥Ç
Junction temperature			Tj max.		175	°C
THERMAL RESISTANCE						
From junction to ambient in free air	rom junction to ambient in free air			R _{th j-a} =		°C/W
From junction to mounting base			R _{th j-mb} =		3	°C/W
From mounting base to heatsink			R _{th mb-h} =		0.5	oC\M
CHARACTERISTICS						
Forward voltage at IF = I5 A; T _j = 25	6 °C		ν _F <		1, 4	V 1)
Reverse current at VR = VRWMmax; Tj = 125 °C			$I_{\mathbf{R}}$	<	200	μA

MOUNTING INSTRUCTIONS

The top connector should neither be bent nor twisted; it should be soldered into the circuit so that there is no strain on it.

During soldering the heat conduction to the junction should be kept to a minimum.